

TRANSIENT PROTECTION PRODUCTS

"FemtoFarad" Polymer ESD Suppressor

PRODUCT PREVIEW

DESCRIPTION

The "FemtoFarad" product family is specifically designed to protect sensitive electronic circuits from the threat of electrostatic discharge (ESD). "FemtoFarad" products react almost instantly to the transient voltage and effectively clamp it below 60 V, meaning less voltage stress during the clamp period and greater IC protection. The design of "FemtoFarad" products inherently produces a low capacitance part. In the off-state "FemtoFarad" is virtually invisible to the circuit. Installed from signal line to ground, the "FemtoFarad" device exhibits a high impedance and low capacitance that makes it transparent to high-speed digital circuits. Signals are not distorted or disrupted.

With "FemtoFarad" devices, waveform definition stays true and highspeed signals do not suffer.

"FemtoFarad" products utilize a unique polymer-based material. The nature of the material creates a Bidirectional part, which means that only one device is required to provide complete ESD protection regardless of the surge polarity. The combination of this material with proven thick film on ceramic technology produces a reliable, surface mount product that will help protect mobile communications, computers, data processing, test equipment, and many other electronic applications from ESD.

KEY FEATURES

- Exceeds testing requirements outlined in IEC 1000-4-2
- Extremely low capacitance
- Very low leakage current
- Fast response time
- Bidirectional
- Surface mount
- Nickel & Tin/Lead plated

APPLICATIONS/BENEFITS

- GaAs & InGaAs Photodetector protection
- InGaP HBT Power Amplifier Protection
- High Speed Data Line Protection
- Mobile Phone ESD protection

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

Part Ratings and Characteristics						
Performance Characteristics	Min	Тур	Max	Units		
Continuous operating voltage	ı	-	6	VDC		
Clamping voltage ¹	ì	35	60	V		
Trigger voltage ²	ï	150	300	V		
ESD voltage capability ⁴	ì	8	15	kV		
Capacitance (@ 1 MHz)	ı	0.25	1	pF		
Leakage current (@ 6 VDC)	ı	<10	<100	nA		
Peak current ^{1, 4}	1	30	45	A		
Operating temperature	-40	+25	+85	°C		
ESD pulse withstand ^{1,3}	20	-	-	# pulses		



Notes:

- 1. Per IEC 1000-4-2, 30A @ 8kV, level 4, clamping measurements made 30 ns after initiation of pulse, all tests in contact discharge mode.
- 2. Trigger measurement made using TLP method (see page5).
- 3. Parts will remain within the specifications listed in the above table through a minimum of 20 ESD pulses.
- 4. TVSF0805 devices are capable of withstanding up to a 15 kV, 45 A ESD pulse. Device ratings are given at 8 kV per Note 1 unless otherwise specified.

Environmental Specifications;

- Humidity, steady state: MIL-STD-202F, Method 103B, 90-95% RH, 40°C, 96 hrs.
- Thermal shock: MIL-STD-202, Method 107G, -65°C to 125°C, 30 min. cycle 5 cycles
- Vibration: MIL STD-202F, Method 201A, (10 to 55 to 10 Hz, 1 min. cycle, 2 hrs each in X-Y-Z)
- Chemical resistance: ASTM D-543, 24 hrs @ 50°C, 3 solutions (H₂0, detergent solution, defluxer)
- Full Load voltage: 24 VDC, 1000 hrs, 25°C
- Solder leach resistance and terminal adhesion: Per EIA-576
- Solderability: MIL-STD-202, Method 208 (95% coverage)



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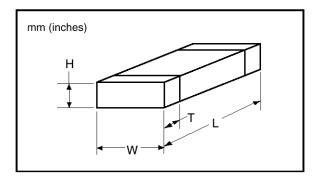
Definition of Terms:

Clamping Voltage – The voltage at which the "FemtoFarad" device stabilizes during the transition from high to low impedance. This is the voltage experienced by the circuit, after stabilizing, for the duration of the ESD transient.

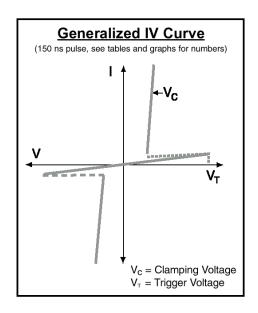
Trigger Voltage – The voltage at which the "FemtoFarad" device begins to function. When the ESD threat voltage reaches this level, the "FemtoFarad" device begins the transition from high impedance to low impedance, shunting the ESD energy to ground.

Threat Voltage – The voltage that the test equipment is set to operate (i.e. the voltage across the discharge capacitor).

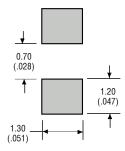
Product Dimension



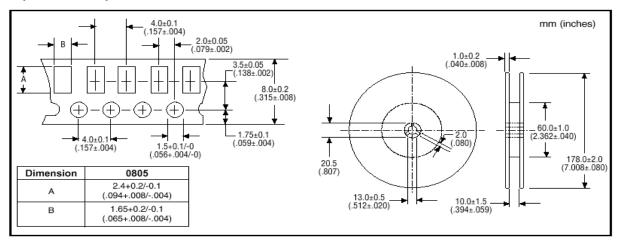
EIA Size	L	w	Н	Т
0805	2.0 ± 0.20	1.20 ± 0.20	0.70 ± 0.10	0.30 ± 0.20
	(.079 ± .008)	(.047 ± .008)	(.028 ± .004)	(.012 ± .008)



Recommended Solder Pad Outline (per IPC-SM-782)



Tape and Reel Specification



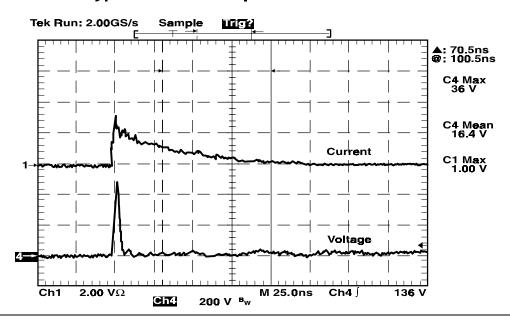


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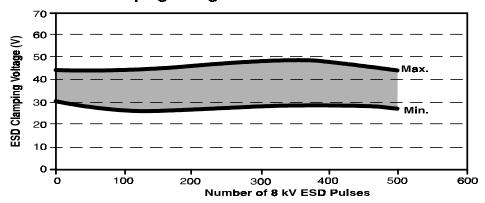
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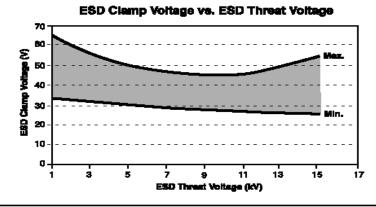
"FemtoFarad" TVSF0805 Device Performance

Typical Device Response to 8kV ESD



ESD Clamping Voltage vs. Number of 8 kV ESD Pulses





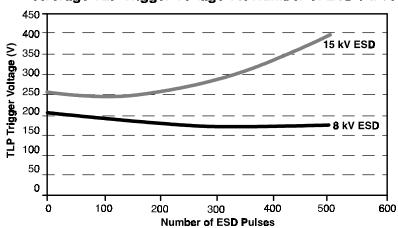


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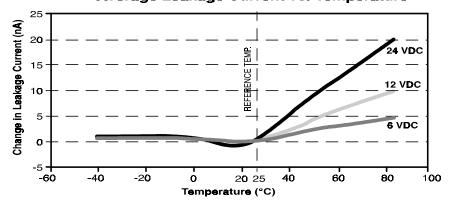
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"FemtoFarad" TVSF0805 Device Performance

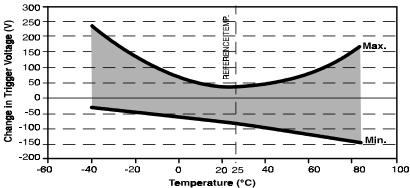
Average TLP Trigger Voltage vs. Number of ESD Pulses



Average Leakage Current vs. Temperature









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Test Methodology

Full product characterization requires testing in a variety of scenarios. Different test methods reveal unique information about the device response. Evaluating the results for all of the tests is crucial to fully understanding the device operation. Two different test methods have been employed to understand the "FemtoFarad" device response to an over voltage event.

Electrostatic Discharge (ESD) pulse

The ESD pulse is the defining test for an ESD protective device. The ESD pulse is an extremely fast rising transient event. The pulse is characterized in IEC 1000-4-2, has arise time of less than 1 ns, peak currents up to 45 A, and voltage levels to 15kV. Characteristics determined by this test are those such as voltage overshoot, peak voltage, clamping voltage, and peak current.

Due to the extremely fast rate of rise of the ESD pulse, the test setup can have a definite impact on the above factors. Variable such as wiring inductance and probe capacitance can produce inaccurate readings on an otherwise capable oscilloscope.

Transmission Line Pulse (TLP)

The transmission line tester implements a controlled impedance cable to deliver a square wave current pulse. The advantage of this technique is that the constant current of the square wave allows the behavior of the protection structure to be more studied.

The actual implementation of this technique produces a waveform that has a slightly slower rise time than the ESD pulse but can be correlated to deliver approximately the same surge current and energy. This controlled impedance pulse provides a more accurate depiction of the trigger voltage of the device because of the reduced voltage overshoot caused by a fast rising transient and the reactive components of the test fixture.

Device Application

TVSF0805 "FemtoFarad" devices are applicable to signal line circuits. It is applied in a shunt-connected manner. These devices are not applicable on line where lightning or load switching transients are present. The devices are ideal for use in computers and computer-related equipment, such as modems, keyboards, and printers. The TVSF devices are also well suited for portable electronic equipment such as mobile telephones, test equipment, and card scanners.

Typical Applications

